

# isc N-Channel MOSFET Transistor IRFR18N15D, IIRFR18N15D

### FEATURES

- Static drain-source on-resistance:
  R<sub>DS</sub>(on)≤125mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

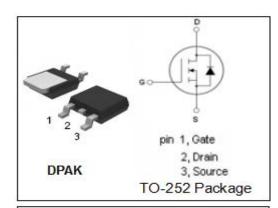
· High frequency DC-DC converters

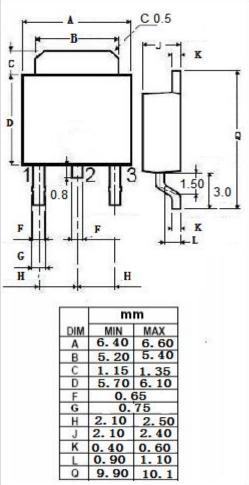
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{ extsf{DSS}}$	Drain-Source Voltage	150	V	
V <sub>GS</sub>	Gate-Source Voltage	±30	V	
ID	Drain Current-Continuous	18	Α	
I <sub>DM</sub>	Drain Current-Single Pulsed	72	А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	110	W	
Tj	Max. Operating Junction Temperature	175	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~175	$^{\circ}$	

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.4	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	110	°C/W







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## **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	150			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250 μ A	3		5.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =11A			125	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =150V; V <sub>GS</sub> = 0V			25	μА
V <sub>SD</sub>	Diode forward voltage	I <sub>s</sub> =11A, V <sub>GS</sub> = 0V			1.5	V

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